NSN 5961-00-383-5545

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-383-5545 **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.017 inches **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 6.0 emitter to base voltage, static, collector open all transistor and 45.0 collector to base voltage/static/emitter open all transistor and 45.0 collector-to-emitter, substaining voltage, base open-circuited all transistor **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 0.9 static forward current transfer ratio, common-emitter all transistor and 1.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: